



12500 TI Boulevard, MS 8640, Dallas, Texas 75243

**PCN#20230306002.1A**

**Qualification of CFAB & DFAB8 as additional Fab sites, Additional AT options, and Cu bond wire  
Change Notification / Sample Request**

**Date:** March 17, 2023

**To:** TOKYO ELECTRON DEVICE (DSTR) PCN

Dear Customer:

**Revision A** is to include devices in page 2 of this letter that were not previously included.

This is an announcement of a change to a device that is currently offered by Texas Instruments (TI). The details of this change are on the following pages, and are in alignment with our standard product change notification (PCN) [process](#).

TI requires acknowledgement of receipt of this notification within 30 days of the date of this notice. Lack of acknowledgement of this notice within 30 days constitutes acceptance of the change. If samples or additional data are required, requests must be received within 30 days of this notification, given that samples are not built ahead of the change.

The Proposed First Ship date in this PCN letter is the earliest possible date that customers could receive the changed material. It is our commitment that the changed device will not ship before that date. If samples are requested within the 30 day sample request window, customers will still have 30-days to complete their evaluation regardless of the proposed 1st ship date.

This particular PCN is related to TI's multiyear transition plan for our two remaining factories with 150-millimeter production (DFAB in Dallas, Texas, and SFAB in Sherman, Texas). DFAB will remain open, but will focus on 200-mm production, with a smaller set of technologies. SFAB will close no earlier than 2024 and no later than 2025. As referenced in the "reason for change" below, these changes are part of our multiyear plan to transition these products to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

For questions regarding this notice or to provide acknowledgement of this PCN, you may contact your local Field Sales Representative or the PCN Team ([PCN\\_admin\\_team@list.ti.com](mailto:PCN_admin_team@list.ti.com)). For sample requests or sample related questions, contact your local Field Sales Representative. As always, we thank you for your continued business.

PCN Team  
SC Business Services

## 20230306002.1A

### Attachment: 1

#### Products Affected:

The devices listed on this page are a subset of the complete list of affected devices. According to our records, these are the devices that you have purchased within the twenty-four (24) months. The corresponding customer part number is also listed, if available.

DEVICE	CUSTOMER PART NUMBER
TPS3619-33DGKR	null
TPS3838J25DBVT	null
TPS3619-33DGK	null
TPS3838K33DBVT	null

Technical details of this Product Change follow on the next page(s).

<b>PCN Number:</b>	20230306002.1A	<b>PCN Date:</b>	March 17, 2023
<b>Title:</b>	Qualification of CFAB & DFAB8 as additional Fab sites, Additional AT options, and Cu bond wire		
<b>Customer Contact:</b>	<a href="#">PCN Manager</a>	<b>Dept:</b>	Quality Services
<b>Proposed 1<sup>st</sup> Ship Date:</b>	Jun 5, 2023	<b>Sample requests accepted until:</b>	April 7, 2023*

**\*Sample requests received after April 7, 2023 will not be supported.**

<b>Change Type:</b>					
<input checked="" type="checkbox"/>	Assembly Site	<input checked="" type="checkbox"/>	Assembly Process	<input checked="" type="checkbox"/>	Assembly Materials
<input type="checkbox"/>	Design	<input type="checkbox"/>	Electrical Specification	<input type="checkbox"/>	Mechanical Specification
<input type="checkbox"/>	Test Site	<input type="checkbox"/>	Packing/Shipping/Labeling	<input type="checkbox"/>	Test Process
<input type="checkbox"/>	Wafer Bump Site	<input type="checkbox"/>	Wafer Bump Material	<input type="checkbox"/>	Wafer Bump Process
<input checked="" type="checkbox"/>	Wafer Fab Site	<input checked="" type="checkbox"/>	Wafer Fab Materials	<input type="checkbox"/>	Wafer Fab Process
		<input type="checkbox"/>	Part number change		

### PCN Details

#### Description of Change:

**Revision A** is to include devices in page 2 of this letter that were not previously included.

Qualification of additional Fab sites (CFAB & DL-LIN) using qualified Process Technology and additional Assembly sites options for the list of devices in the product affected section below.

Current Fab Site			Additional Fab Site		
Current Fab Site	Process	Wafer Diameter	Additional Fab Site	Process	Wafer Diameter
DL-LIN	LBC3S	150mm	CFAB	LBC3S	200mm
			DL-LIN		

Construction differences (No construction differences for Groups 1 & 6) are as follows:

#### Group 2: CFAB & DFAB as an additional Fab sites and Cu as additional bond wire

	Current	Additional
Bond wire composition, diameter	Au, 0.96 mil	Cu, 0.96 mil

#### Group 3: CFAB & DFAB8 as additional fab sites and additional AT sites

	LEN	TAI	UTL1	CDAT	FMX	MLA
Mold Compound	SID #0011G60007	4205443 or 4211880	SID #CZ0135	4222198	4211880	4211649
Bond wire composition, diameter	Au, 1.0 mil	Au, 0.96 mil	Cu, 1.0 mil	Cu, 0.8 or 1.0 mil	Cu, 0.96	Cu, 0.96 mil
Mount Compound	SID #0003C10332	4208458 or 4147858	SID #PZ0037	4226215, or 4207123	4147858	4208458
Lead finish	NiPdAu	NiPdAu	NiPdAu	NiPdAu or Matte Sn	NiPdAu	NiPdAu
Final Test site	LEN	TAI	UTL2	CDAT	FMX	MLA

Upon expiry of this PCN TI will combine lead free solutions in a single **standard part number**, for the devices in group 3. For example; **TPS3838E18DBVT** – can ship with both Matte Sn and NiPdAu/Ag.

Example:

- Customer order for 7500 units of TPS3838E18DBVT with 2500 units SPQ (Standard Pack Quantity per Reel).

- TI can satisfy the above order in one of the following ways.
  - I. 3 Reels of NiPdAu finish.
  - II. 3 Reels of Matte Sn finish
  - III. 2 Reels of Matte Sn and 1 reel of NiPdAu finish.
  - IV. 2 Reels of NiPdAu and 1 reel of Matte Sn finish.

Qual details are provided in the Qual Data Section.

#### Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-millimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

#### Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

#### Impact on Environmental Ratings

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS	REACH	Green Status	IEC 62474
<input checked="" type="checkbox"/> No Change	<input checked="" type="checkbox"/> No Change	<input checked="" type="checkbox"/> No Change	<input checked="" type="checkbox"/> No Change

#### Changes to product identification resulting from this PCN:

##### Fab Site Information:


Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City
DL-LIN	DLN	USA	Dallas
<b>CFAB</b>	<b>CU3</b>	<b>CHN</b>	<b>Chengdu</b>

##### Assembly Site Information:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City
TAI	TAI	TWN	Chung Ho, New Taipei City
LEN	LIN	TWN	Taichung
UTL1	NSE	THA	Bangkok
<b>CDAT</b>	<b>CDA</b>	<b>CHN</b>	<b>Chengdu</b>
<b>TI Malaysia</b>	<b>MLA</b>	<b>MYS</b>	<b>Kuala Lumpur</b>
<b>FMX</b>	<b>MEX</b>	<b>MEX</b>	<b>Aguascalientes</b>

Sample product shipping label (not actual product label)

**TEXAS INSTRUMENTS**  
 MADE IN: Malaysia  
 2DC: 20:  
 MSL 2 / 260C/1 YEAR SEAL DT  
 MSL 1 / 235C/UNLIM 03/29/04  
 OPT:  
 ITEM: 39  
**LBL: 5A (L)T0:1750**



(1P) **SN74LS07NSR**  
 (Q) **2000** (D) **0336**  
 (31T) LOT: 3959047MLA  
 (4W) TKY (1T) 7523483SI2  
 (P)  
 (2P) REV: (V) 0000017  
 (20L) CS0: SHE (21L) CC0:USA  
 (22L) AS0: MLA (23L) AC0: MYS

**Product Affected:**

**Group 1 (CFAB & DFAB8 as additional Fab sites) Device list:**

SN65C3238DBR	TPS3619-33DGKR	TPS3838J25DBVR	TPS3838L30DBVR
SN65C3238PWR	TPS3838E18DBVR	TPS3838K33DBVR	TPS3838L30DBVT
TLV2462AQDRG4	TPS3838E18DBVT	TPS3838K33DBVT	TPS3838J25DBVT
TPS3619-33DGK			

**Group 2 (CFAB & DFAB as an additional Fab sites and Cu as additional bond wire) Device list:**

TLV2462AQD	TLV2462AQPWR	TLV2462QPWR	TLV2462QPWRG4
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**Group 3 (CFAB & DFAB8 as additional fab sites and additional AT sites) Device list:**

TLC2264AQD	TLC2264AQDRG4	TPS3838K33DRVR	TPS3838K33DRVT
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**Group 6 (CFAB as an additional fab only) Device list:**

DRV602PW	TLC2274AMDRG4	TLV2462IDGKR	TLV2463IDGS
DRV602PWR	TLV2462CDGKR	TLV2463CDGSR	TLV2463IDGSR
TCA4311ADGKR			

For alternate parts with similar or improved performance, please visit the product page on [TI.com](http://TI.com)

**Qualification Results**  
Data Displayed as: Number of lots / Total sample size / Total failed

Type	Test Name / Condition	Duration	Qual Device: TLC2264AQPWRQ1	Qual Device: TLC2264AIDRCT	QBS Process Reference: CD3301RHR	QBS Package Reference: TLV9064QPWRQ1
HTOL	Life Test, 150C	300 Hours	1/3/0	-	3/231/0	-
HTSL	High Temp Storage Bake 170C	420 Hours	-	-	3/231/0	1/45/0
HAST	Biased HAST, 130C/85%RH	96 Hours	-	-	3/231/0	-
AC	Autoclave 121C	96 Hours	-	-	3/231/0	3/231/0
TC	Temperature Cycle, -65/150C	500 Cycles	-	-	3/231/0	3/231/0
HBM	ESD - HBM	2000 V	1/3/0	-	1/3/0	-
CDM	ESD - CDM	750 V	1/3/0	-	1/3/0	-
LU	Latch-up	(per JESD78)	1/6/0	-	1/6/0	-
ED	Electrical Characterization	Per Datasheet Parameters	1/30/0	-	1/30/0	-
MQ	Assembly MQ	Per Site Specifications	Pass	Pass	Pass	Pass

- QBS: Qual By Similarity  
- Qual Device TLC2264AQPWRQ1s qualified at LEVEL 1-260C  
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable  
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours  
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours  
- The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles  
Quality and Environmental data is available at TI's external Web site: <http://www.ti.com/>

**Green/Pb-free Status:**

Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20200903-135990



**Automotive New Product Qualification Summary**  
(As per AEC-Q100 and JEDEC Guidelines)

**Approved 2-March-2023**

**Qualification Results**  
Data Displayed as: Number of lots / Total sample size / Total failed

Type	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: SN65HVD4195QDRQ1
<b>Test Group A – Accelerated Environment Stress Tests</b>							
PC	A1	JEDEC J-STD-020 JESD22-A113	3	231	Automotive Preconditioning	Level 1-260C	Pass
bHAST	A2	JEDEC JESD22-A101	3	77	Biased HAST, 130C/85%RH	192 Hours	3/231/0
AC	A3	JEDEC JESD22-A102	3	77	Autoclave, 121C	192 Hours	3/231/0
TC	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle, -65/150C	500 Cycles	3/231/0
HTSL	A6	JEDEC JESD22-A103	1	45	High Temp. Storage Life, 175C	500 Hours	1/45/0
<b>Test Group B – Accelerated Lifetime Simulation Tests</b>							
HTOL	B1	JEDEC JESD22-A108	3	77	Life Test, 125C	1000 Hours	3/231/0
ELFR	B2	AEC Q100-008	3	800	Early Life Failure Rate, 125C	48 Hours	3/2400/0
<b>Test Group C – Package Assembly Integrity Tests</b>							
WBS	C1	AEC Q100-001	1	30	Bond Shear (Cpk>1.67)	Wires	3/90/0
WBP	C2	MIL-STD883 Method 2011	1	30	Bond Pull (Cpk>1.67)	Wires	3/90/0
SD	C3	JEDEC JESD22-B102	1	15	Surface Mount Solderability >95% Lead Coverage	15	1/15/0
PD	C4	JEDEC JESD22-B100 and B108	3	10	Physical Dimensions (Cpk>1.67)	10 units	3/30/0
<b>Test Group D – Die Fabrication Reliability Tests</b>							
EM	D1	JESD61	-	-	Electromigration	--	Completed Per Process Technology Requirements
TDD8	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	--	Completed Per Process Technology Requirements
HCI	D3	JESD60 & 28	-	-	Hot Injection Carrier	--	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	--	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	--	Completed Per Process Technology Requirements

Test Group E – Electrical Verification Tests								
	HBM	E2	AEC Q100-002	1	3	ESD - HBM	2000 V	1/3/0
	CDM	E3	AEC Q100-011	1	3	ESD - CDM	1000 V	1/3/0
	LU	E4	AEC Q100-004	1	6	Latch-up	+/-100mA, 125C	1/6/0
	ED	E5	AEC Q100-005	3	30	Electrical Distribution	Cpk > 1.67	3/30/0

- QBS: Qual By Similarity

- Qual Device TPS3838E18QDBVRCT is qualified at LEVEL1-260C

#### A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

#### Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C

Grade 1 (or Q): -40°C to +125°C

Grade 2 (or T): -40°C to +105°C

Grade 3 (or I): -40°C to +85°C

#### E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

#### Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

TI Qualification ID: R-CHG-2211-005



TI Information  
Selective Disclosure

### Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Approve Date 11-Feb-2020

Updated 02/11/2020-Added QBS Data

#### Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

Type	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: TLV2401QDBVRQ1	QBS Process Reference: MAX3243IPWG4DL
Test Group A – Accelerated Environment Stress Tests								
PC	A1	JEDEC J-STD-020 JESD22-A113	3	77	Automotive Preconditioning Level 1	Level 1-260C	3/1199/0	-
HAST	A2	JEDEC JESD22-A110	3	77	Biased HAST, 130C/85%RH	96 Hours	3/231/0	3/231/0
AC	A3	JEDEC JESD22-A102	3	77	Autoclave 121C	96 Hours	3/231/0	3/231/0
TC	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle, -65/150C	500 Cycles	3/231/0	3/231/0
PTC	A5	JEDEC JESD22-A105	1	45	Power Temperature Cycle	1000 Cycles	N/A	-
HTSL	A6	JEDEC JESD22-A103	1	45	High Temp Storage Bake 150C	1000 Hours	-	3/231/0
HTSL	A8	JEDEC JESD22-A103	1	45	High Temp Storage Bake 175C	500 Hours	3/135/0	-
Test Group B – Accelerated Lifetime Simulation Tests								
HTOL	B1	JEDEC JESD22-A108	3	77	Life Test, 150C	408 Hours	3/231/0	3/231/0
ELFR	B2	AEC Q100-008	3	800	Early Life Failure Rate, 125C	48 Hours	-	3/2400/0
EDR	B3	AEC Q100-005	3	77	NVM Endurance, Data Retention, and Operational Life	-	N/A	-
Test Group C – Package Assembly Integrity Tests								
WBP	C1	AEC Q100-001	1	30	Bond Pull, over ball	Minimum of 5 devices, 30 wires Cpk>1.67	3/90/0	1/30/0
WBP	C1	AEC Q100-001	1	30	Bond Pull, over stitch	Minimum of 5 devices, 30 wires Cpk>1.67	3/90/0	1/30/0
WBS	C1	AEC Q100-001	1	30	Auto Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	3/90/0	-

Type	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: TLV2401QDBVRQ1	QBS Process Reference: MAX3243IPWG4DL
SD	C3	JEDEC JESD22-B102	1	15	Surface Mount Solderability	Pb	1/15/0	-
SD	C3	JEDEC JESD22-B102	1	15	Surface Mount Solderability	Pb Free	1/15/0	1/15/0
PD	C4	JEDEC JESD22-B100 and B108	3	10	Auto Physical Dimensions	Cpk>1.67	3/30/0	3/30/0
LI	C6	JEDEC JESD22-B105	1	22	Lead Pull to Destruction	Leads	1/22/0	-
<b>Test Group D – Die Fabrication Reliability Tests</b>								
EM	D1	JESD61	-	-	Electromigration	-	Completed Per Process Technology Requirements	-
TDD8	D2	JESD35	-	-	Time Dependant Dielectric Breakdown	-	Completed Per Process Technology Requirements	-
HCI	D3	JESD60 & 28	-	-	Hot Injection Carrier	-	Completed Per Process Technology Requirements	-
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	Completed Per Process Technology Requirements	-
SM	D5	-	-	-	Stress Migration	-	Completed Per Process Technology Requirements	-
<b>Test Group E – Electrical Verification Tests</b>								
HBM	E2	AEC Q100-002	1	3	ESD - HBM - Q100	500 V (1)	1/3/0	-
CDM	E3	AEC Q100-011	1	3	ESD - CDM - Q100	1500 V	1/3/0	-
LU	E4	AEC Q100-004	1	6	Latch-up	Per AEC-Q100-004	1/6/0	-
ED	E5	AEC Q100-009	3	30	Auto Electrical Distributions	Cpk>1.67	3/90/0	-

- QBS: Qual By Similarity

- Qual Device TLV2401QDBVRQ1 is qualified at LEVEL 1-260C

**A1 (PC): Preconditioning:**

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

**Ambient Operating Temperature by Automotive Grade Level:**

Grade 0 (or E): -40°C to +150°C

Grade 1 (or Q): -40°C to +125°C

Grade 2 (or T): -40°C to +105°C

Grade 3 (or I): -40°C to +85°C

**E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):**

Room/Hot/Cold: HTOL, ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

**Green/Pb-free Status:**

Qualified Pb-Free(SMT) and Green

Note (1): See ESD waiver attached to eQDB.

Change Number: NA

TI Qualification ID: 20190124-128331



**Automotive New Product Qualification Summary  
(As per AEC-Q100 and JEDEC Guidelines)**

**Q006 Qual Summary for LBC3 BOAC with PCC wire in FMX with 150mm wafers (ALSiCu metalization) Q100H (Grade 1, -40/125C)**

**Approved 07-Sep-2016**

**Product Attributes**

Attributes	Qual Device: SN65HVD233QDRQ1	Qual Device: SN65HVD234QDRQ1	Qual Device: SN65HVD235QDRQ1
Automotive Grade Level	Grade 1	Grade 1	Grade 1
Operating Temp Range	-40 to +125 C	-40 to +125 C	-40 to +125 C
Product Function	Interface	Interface	Interface
Wafer Fab Supplier	DFAB	DFAB	DFAB
Die Revision	A	A	A
Assembly Site	FMX	FMX	FMX
Package Type	SOIC	SOIC	SOIC
Package Designator	D	D	D
Ball/Lead Count	8	8	8

- QBS: Qual By Similarity

- Qual Device SN65HVD233QDRQ1, Qual Device SN65HVD235QDRQ1, - Qual Device SN65HVD234QDRQ1 is qualified at LEVEL1-260C

**Qualification Results**

**Data Displayed as: Number of lots / Total sample size / Total failed**

Type	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: SN65HVD233QDRQ1	Qual Device: SN65HVD234QDRQ1	Qual Device: SN65HVD235QDRQ1
<b>Test Group A – Accelerated Environment Stress Tests</b>									
-	-	-	-	-	SAM Analysis Post Precon	Completed	1/22/0	1/22/0	1/22/0
PC	A1	JEDEC J-STD-020 JESD22-A113	-	-	Preconditioning	Level 1- 260C	No Fails	No Fails	No Fails
-	-	-	-	-	SAM Analysis Post Precon	Completed	1/22/0	1/22/0	1/22/0
HAST	A2	JEDEC JESD22-A110	3	77	Biased HAST 130C/85%RH	96 Hours	1/77/0	1/77/0	1/77/0
-	-	-	3	1	Cross Section Post bHAST 96 Hours	Completed	1/1/0	1/1/0	1/1/0

Type	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: SN65HVD233QDRQ1	Qual Device: SN65HVD234QDRQ1	Qual Device: SN65HVD235QDRQ1
-	-	-	3	22	SAM Analysis Post bHAST 96 Hours	Completed	1/22/0	1/22/0	1/22/0
-	-	-	3	30	Wire Bond Shear Post bHAST 96 Hours	Wires	1/30/0	1/30/0	--
-	-	-	3	30	Bond Pull over Stitch, post bHAST, 96 Hours	Wires	1/30/0	1/30/0	-
-	-	-	3	30	Bond Pull over Ball, Post bHAST, 96 Hours	Wires	1/30/0	1/30/0	-
HAST	A2	JEDEC JESD22-A110	3	70	Biased HAST 130C/85%RH	192 Hours	1/70/0	1/70/0	1/70/0
-	-	-	3	1	Cross Section Post bHAST 192 Hours	Completed	1/1/0	1/1/0	1/1/0
-	-	-	3	22	SAM Analysis Post bHAST 192 Hours	Completed	1/22/0	1/22/0	1/22/0
-	-	-	3	30	Wire Bond Shear Post bHAST 192 Hours	Wires	1/20/0 (1)	1/30/0	1/30/0
-	-	-	3	30	Bond Pull over Stitch, post bHAST, 192 Hours	Wires	1/30/0	1/30/0	1/30/0
-	-	-	3	30	Bond Pull over Ball, Post bHAST, 192 Hours	Wires	1/20/0 (1)	1/30/0	1/30/0
TC	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle -65/150C	500 Cycles	1/77/0	1/77/0	1/77/0
-	-	-	3	1	Cross Section Post T/C 500 Cycles	Completed	1/1/0	1/1/0	1/1/0
-	-	-	3	22	SAM Analysis Post T/C 500 Cycles	Completed	1/22/0	1/22/0	1/22/0
TC- WBS	-	-	3	30	Wire Bond Shear Post T/C 500 Cycles	Wires	1/30/0	1/30/0	1/30/0
TC- WBP	A4	MIL-STD883 Method 2011	3	30	Bond Pull over Ball Post T/C 500 Cycles	Wires	1/30/0	1/30/0	1/30/0
TC- WBP	A4	MIL-STD883 Method 2011	3	30	Bond Pull over Stitch Post T/C 500 Cycles	Wires	1/30/0	1/30/0	1/30/0
TC	A4	JEDEC JESD22-A104 and Appendix 3	3	70	Temperature Cycle -65/150C	1000 Cycles	1/70/0	1/70/0	1/70/0
-	-	-	3	1	Cross Section Post T/C 1000 Cycles	Completed	1/1/0	1/1/0	1/1/0
-	-	-	3	22	SAM Analysis Post T/C 1000 Cycles	Completed	1/22/0	1/22/0	1/22/0
TC- WBS	-	-	3	30	Wire Bond Shear Post T/C 1000 Cycles	Wires	1/30/0	1/30/0	1/30/0
TC- WBP	A4	MIL-STD883 Method 2011	3	30	Bond Pull over Ball Post T/C 1000 Cycles	Wires	1/30/0	1/30/0	1/30/0
TC- WBP	A4	MIL-STD883 Method 2011	3	30	Bond Pull over Stitch Post T/C 1000 Cycles	Wires	1/30/0	1/30/0	1/30/0

Type	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: SN65HVD233QDRQ1	Qual Device: SN65HVD234QDRQ1	Qual Device: SN65HVD235QDRQ1
PTC	A5	JEDEC JESD22-A105	1	45	Power Temperature Cycle - 40/125C	1000 Cycles	N/A	N/A	N/A
PTC	A5	JEDEC JESD22-A105	1	45	Power Temperature Cycle - 40/125C	2000 Cycles	N/A	N/A	N/A
HTSL	A6	JEDEC JESD22-A103	3	45	High Temp Storage Bake 150C	1000 Hours	1/45/0	1/45/0	1/45/0
-	-	-	3	1	Cross Section Post Bake 1000 Hours	Completed	1/1/0	1/1/0	1/1/0
HTSL	A6	JEDEC JESD22-A103	3	44	High Temp Storage Bake 150C	2000 Hours	1/44/0	1/44/0	1/44/0
-	-	-	3	1	Cross Section Post Bake 2000 Hours	Completed	1/1/0	1/1/0	1/1/0
<b>Test Group C – Package Assembly Integrity Tests</b>									
WBS	C1	AEC Q100-001	3	30	Wire Bond Shear Cpk>1.67	Wires	1/30/0	1/30/0	1/30/0
WBP	C2	MIL-STD883 Method 2011	3	30	Bond Pull Cpk>1.67	Wires	1/30/0	1/30/0	1/30/0

**A1 (PC): Preconditioning:**

Performed for THB, Biased HAST, AC, uHAST & TC samples, as applicable.

**Junction Operating Temperature by Automotive Grade Level:**

Grade 0 (or E): -40°C to +150°C

Grade 1 (or Q): -40°C to +125°C

Grade 2 (or T): -40°C to +105°C

Grade 3 (or I): -40°C to +85°C

**E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):**

Room/Hot/Cold: HTOL, ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

**Green/Pb-free Status:**

Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20160217-116814

**Notes/ Comments:**

(1) Performed on only 2 devices



**TI Information**  
**Selective Disclosure**

## Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

**SN3257QPWRQ1 (Grade 1, Q100H, -40/125C)**  
**Approved 13-Feb-2020**

### Product Attributes

Attributes	Qual Device: SN3257QPWRQ1	QBS Process Reference: SN3257QDYRQ1
Automotive Grade Level	Grade 1	Grade 1
Operating Temp Range	-40 to +125 C	-40 to +125 C
Product Function	Interface	Interface
Wafer Fab Supplier	RFAB	RFAB
Die Revision	A	A
Assembly Site	MLA	PHI
Package Type	TSSOP	SOT-23
Package Designator	PW	DYY
Ball/Lead Count	16	16

- QBS: Qual By Similarity

- Qual Device SN3257QPWRQ1 is qualified at LEVEL1-260C

**Qualification Results**  
**Data Displayed as: Number of lots / Total sample size / Total failed**

Type	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: <u>SN3257QPWRQ1</u>	QBS Process Reference: <u>SN3257QDYRQ1</u>
<b>Test Group A – Accelerated Environment Stress Tests</b>								
PC	A1	JEDEC J-STD-020 JESD22-A113	3	77	Preconditioning	Level 1-260C	No Fails	-
HAST	A2	JEDEC JESD22-A110	3	77	Biased HAST, 130C/85%RH	96 Hours	3/231/0	-
AC	A3	JEDEC JESD22-A102	3	77	Autoclave 121C	96 Hours	3/231/0	-
TC	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle, -55/150C	1000 Cycles	3/231/0	-
TC-WBP	A4	MIL-STD883 Method 2011	1	60	Bond Pull Post Temp Cycle	Wires	1/60/0	-
PTC	A5	JEDEC JESD22-A105	1	45	Power Temperature Cycle	1000 Cycles	N/A	-
HTSL	A6	JEDEC JESD22-A103	1	45	High Temp Storage Bake 175C	500 Hours	3/135/0	-
<b>Test Group B – Accelerated Lifetime Simulation Tests</b>								
HTOL	B1	JEDEC JESD22-A108	3	77	Life Test, 150C	300 Hours	3/231/0	3/231/0
ELFR	B2	AEC Q100-008	3	800	Early Life Failure Rate, 150C	24 Hours	-	3/2400/0
EDR	B3	AEC Q100-005	3	77	NVM Endurance, Data Retention, and Operational Life	-	N/A	-
<b>Test Group C – Package Assembly Integrity Tests</b>								
WBS	C1	AEC Q100-001	1	30	Wire Bond Shear, Cpk >1.67	Wires	3/90/0	-
WBP	C2	MIL-STD883 Method 2011	1	30	Bond Pull, Cpk >1.67	Wires	3/90/0	-
SD	C3	JEDEC JESD22-B102	1	15	Surface Mount Solderability	PB Solder	1/15/0	-
SD	C3	JEDEC JESD22-B102	1	15	Surface Mount Solderability	Pb Free Solder	1/15/0	-
PD	C4	JEDEC JESD22-B100 and B108	3	10	Physical Dimensions	Cpk>1.67	3/30/0	-
<b>Test Group D – Die Fabrication Reliability Tests</b>								
EM	D1	JESD61	-	-	Electromigration	-	Completed Per Process Technology Requirements	-
Tddb	D2	JESD35	-	-	Time Dependant Dielectric Breakdown	-	Completed Per Process Technology Requirements	-
HCI	D3	JESD60 & 28	-	-	Hot Injection Carrier	-	Completed Per Process Technology Requirements	-
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	Completed Per Process Technology Requirements	-
SM	D5	-	-	-	Stress Migration	-	Completed Per Process Technology Requirements	-

Test Group E – Electrical Verification Tests									
	HBM	E2	AEC Q100-002	1	3	ESD - HBM	5000 V	1/3/0	-
	CDM	E3	AEC Q100-011	1	3	ESD - CDM	2000 V	1/3/0	-
	LU	E4	AEC Q100-004	1	6	Latch-up	Per AEC Q100-004	1/6/0	-
	ED	E5	AEC Q100-009	3	30	Electrical Distributions	Cpk >1.67	3/90/0	-

#### A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

#### Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C

Grade 1 (or Q): -40°C to +125°C

Grade 2 (or T): -40°C to +105°C

Grade 3 (or I): -40°C to +85°C

#### E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold: HTOL, ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

#### Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20190311-128972



TI Information  
Selective Disclosure

#### Automotive New Product Qualification Summary

(As per AEC-Q100 and JEDEC Guidelines)

**Q100H Grade-1 qual for TLV27L2QDRQ1 (DFAB/LBC3S) in FMX using 8-pin SOIC pkg**

Approved 03-Sep-2015

Updated 08/03/2015-Added QBS Data

Product Attributes

Attributes	Qual Device: TLV2372QDRG4Q1	Qual Device: TLV2372QDRQ1	Qual Device: TLV27L2QDRQ1	QBS Process Reference: MAX3243IPWG4DL	QBS Package Reference: SN65HVD230D	QBS Package Reference: TPS28225TDRQ1
Operating Temp Range	-40°C to +125°C	-40°C to +125°C	-40°C to +125°C	-40°C to +125°C	-40°C to +125°C	-40°C to +105°C
Automotive Grade Level	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 2
Product Function	Signal Chain	Signal Chain	Signal Chain	-	-	-
Water Fab Supplier	DFAB	DFAB	DFAB	DFAB	DFAB	DMOS5
Die Revision	A	A	A	A	B	D
Assembly Site	FMX	FMX	FMX	MLA	FMX	FMX
Package Type	SOIC	SOIC	SOIC	TSSOP	SOIC	SOIC
Package Designator	D	D	D	PW	D	D
Ball/Lead Count	8	8	8	28	8	8

QBS: Qual By Similarity

- Qual Devices qualified at LEVEL1-200C: TLV2372QDRG4Q1, TLV2372QDRQ1, TLV27L2QDRQ1

Type	#	Test Spec	Min Lot Qty	SS/ Lot	Test Name / Condition	Duration	Qual Device: TLV2372QDRG4Q1	Qual Device: TLV2372QDRQ1	Qual Device: TLV27L2QDRQ1	QBS Process Reference: MAX3243IPWG4DL	QBS Package Reference: SN65HVD230D	QBS Package Reference: TPS28225TDRQ1
Test Group A – Accelerated Environment Stress Tests												
PC	A1	JEDEC J-STD-020 JESD22-A113	1	0	Automotive Preconditioning	Level 3-260C	1/243/0	1/240/0	1/300/0	-	-	-
THB	A2	JEDEC JESD22-A101	3		Biased Temperature and Humidity, 85C/85%RH	1000 Hours	1/77/1 (Note 1)	1/77/0	-	-	-	-
HAST	A2	JEDEC JESD22-A110	1	77	Biased HAST, 130C/85%RH	96 Hours	-	-	1/77/0	3/231/0	-	-
AC	A3	JEDEC JESD22-A102	1	77	Autoclave 121C	96 Hours	1/77/0	1/77/0	1/77/0	3/231/0	-	-
TC	A4	JEDEC JESD22-A104 and Appendix 3	1	77	Temperature Cycle, -65/150C	500 Cycles	1/77/0	1/77/0	1/77/0	3/231/0	-	-
TC-BP		MIL-STD883 Method 2011	1	30	Post Temp Cycle Bond Pull	Wires	-	-	1/30/0	-	-	-
PTC	A5	JEDEC JESD22-A105	1		Power Temperature Cycle, -40/105C	1000 Cycles	N/A	N/A	N/A	-	-	-
HTSL	A6	JEDEC JESD22-A103	1	45	High Temp. Storage Bake, 150C	1000 Hours	-	-	-	1/45/0	-	-
HTSL	A6	JEDEC JESD22-A103	1	45	High Temp. Storage Bake, 175C	500 Hours	-	-	1/45/0	-	-	-
Test Group B – Accelerated Lifetime Simulation Tests												
HTOL	B1	JEDEC JESD22-A108	1	77	Life Test, 150C	408 Hours	1/77/0	1/77/0	1/77/0	3/231/0	-	-
ELFR	B2	AEC Q100-008	3		Early Life Failure Rate, 125C	48 Hours	-	-	-	1/800/0	-	-
ELFR	B2	AEC Q100-008	3		Early Life Failure Rate, 150C	48 Hours	-	-	-	2/1600/0	-	-
EDR	B3	AEC Q100-005	3		NVM Endurance, Data Retention, and Operational Life	-	N/A	N/A	N/A	-	-	-

Test Group C – Package Assembly Integrity Tests											
WBS	C1	AEC Q100-001	1	30	Bond Shear (Cpk>1.67)	Wires	-	-	1/30/0	-	-
WBP	C2	MIL-STD883 Method 2011	1	30	Bond Pull (Cpk>1.67)	Wires	-	-	1/30/0	-	-
SD	C3	JEDEC JESD22-B102	1	15	Surface Mount Solderability	Pb	-	-	-	-	1/15/0
SD	C3	JEDEC JESD22-B102	1	15	Surface Mount Solderability	Pb-Free	-	-	-	-	1/15/0
PD	C4	JEDEC JESD22-B100 and B108	3		Physical Dimensions (Cpk>1.67)	--	-	-	-	3/30/0	3/30/0
Test Group E – Electrical Verification Tests											
HBM	E2	AEC Q100-002	1	3	ESD - HBM	2000 V	-	-	1/3/0	-	-
CDM	E3	AEC Q100-011	1	3	ESD - CDM	1000 V	-	-	1/3/0	-	-
LU	E4	AEC Q100-004	1	6	Latch-up	(Per AEC-Q100-004)	-	-	1/6/0	-	-
ED	E5	AEC Q100-009	3	30	Electrical Distributions	Cpk>1.67	-	-	3/90/0	-	-

A1 (PC): Preconditioning:  
Performed for THB, Biased HAST, AC, uHAST & TC samples, as applicable.

**Junction Operating Temperature by Automotive Grade Level:**

Grade 0 (or E): -40°C to +150°C

Grade 1 (or Q): -40°C to +125°C

Grade 2 (or T): -40°C to +105°C

Grade 3 (or I): -40°C to +85°C

**E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):**

Room/Hot/Cold: HTOL, ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room: AC/uHAST

**Green/Pb-free Status:**

Qualified Pb-Free(SMT) and Green

Note (1): Die EOS, 1 unit – capacitor pinhole, discounted (QTS 439122-1)

TI Qualification ID: 20150513-113887

For questions regarding this notice, e-mails can be sent to the contact below or your local Field Sales Representative.

Location	E-Mail
WW Change Management Team	<a href="mailto:PCN_ww_admin_team@list.ti.com">PCN_ww_admin_team@list.ti.com</a>

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